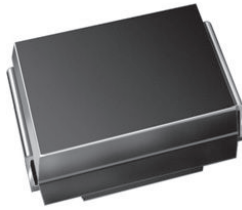


Surface Mount Schottky Barrier Rectifier



SMB (DO-214AA)

FEATURES

- Low profile package
- Ideal for automated placement
- Guardring for overvoltage protection
- Low power losses, high efficiency
- Low forward voltage drop
- High surge capability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified available
 - Automotive ordering code: base P/NHE3 or P/NHM3



RoHS
COMPLIANT
HALOGEN
FREE
Available

PRIMARY CHARACTERISTICS

$I_{F(AV)}$	2.0 A
V_{RRM}	20 V, 30 V, 40 V, 50 V, 60 V
I_{FSM}	75 A
V_F	0.50 V, 0.70 V
T_J max.	150 °C
Package	SMB (DO-214AA)
Diode variations	Single

TYPICAL APPLICATIONS

For use in low voltage high frequency inverters, freewheeling, DC/DC converters, and polarity protection applications.

MECHANICAL DATA

Case: SMB (DO-214AA)

Molding compound meets UL 94 V-0 flammability rating

Base P/N-E3 - RoHS-compliant, commercial grade

Base P/N-M3 - halogen-free, RoHS-compliant, commercial grade

Base P/NHE3_X - RoHS-compliant and AEC-Q101 qualified

Base P/NHM3_X - halogen-free, RoHS-compliant, and AEC-Q101 qualified

("_X" denotes revision code e.g. A, B,)

Terminals: matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

E3, M3, HE3, and HM3 suffix meets JESD 201 class 2 whisker test

Polarity: color band denotes cathode end

MAXIMUM RATINGS ($T_A = 25\text{ °C}$ unless otherwise noted)

PARAMETER	SYMBOL	SS22	SS23	SS24	SS25	SS26	UNIT
Device marking code		S2	S3	S4	S5	S6	
Maximum repetitive peak reverse voltage	V_{RRM}	20	30	40	50	60	V
Maximum RMS voltage	V_{RMS}	14	21	28	35	42	V
Maximum DC blocking voltage	V_{DC}	20	30	40	50	60	V
Max. average forward rectified current at T_L (fig. 1)	$I_{F(AV)}$	2.0					A
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	I_{FSM}	75					A
Non-repetitive avalanche energy at $T_A = 25\text{ °C}$, $I_{AS} = 2.0\text{ A}$, $L = 10\text{ mH}$	E_{AS}	20					mJ
Electrostatic discharge capacitor voltage Human body model: $C = 100\text{ pF}$, $R = 1.5\text{ k}\Omega$	V_C	8.0					kV
Voltage rate of change (rated V_R)	dV/dt	10 000					V/ μ s
Operating junction temperature range	T_J	-65 to +150					°C
Storage temperature range	T_{STG}	-65 to +150					°C

ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)								
PARAMETER	TEST CONDITIONS	SYMBOL	SS22	SS23	SS24	SS25	SS26	UNIT
Maximum instantaneous forward voltage ⁽¹⁾	2.0 A	V _F	0.5			0.7		V
Maximum DC reverse current at rated DC blocking voltage ⁽¹⁾	T _A = 25 °C	I _R	0.4					mA
	T _A = 100 °C		10					

Note

⁽¹⁾ Pulse test: 300 μs pulse width, 1 % duty cycle

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)							
PARAMETER	SYMBOL	SS22	SS23	SS24	SS25	SS26	UNIT
Typical thermal resistance ⁽¹⁾	R _{θJA}	75					°C/W
	R _{θJL}	17					

Note

⁽¹⁾ PCB mounted with 0.55" x 0.55" (14 mm x 14 mm) copper pad areas

ORDERING INFORMATION (Example)				
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE
SS26-E3/52T	0.096	52T	750	7" diameter plastic tape and reel
SS26-E3/5BT	0.096	5BT	3200	13" diameter plastic tape and reel
SS26HE3_A/H ⁽¹⁾	0.096	H	750	7" diameter plastic tape and reel
SS26HE3_A/I ⁽¹⁾	0.096	I	3200	13" diameter plastic tape and reel
SS26-M3/52T	0.096	52T	750	7" diameter plastic tape and reel
SS26-M3/5BT	0.096	5BT	3200	13" diameter plastic tape and reel
SS26HM3_A/H ⁽¹⁾	0.096	H	750	7" diameter plastic tape and reel
SS26HM3_A/I ⁽¹⁾	0.096	I	3200	13" diameter plastic tape and reel

Note

⁽¹⁾ AEC-Q101 qualified

RATINGS AND CHARACTERISTICS CURVES ($T_A = 25\text{ }^{\circ}\text{C}$ unless otherwise noted)

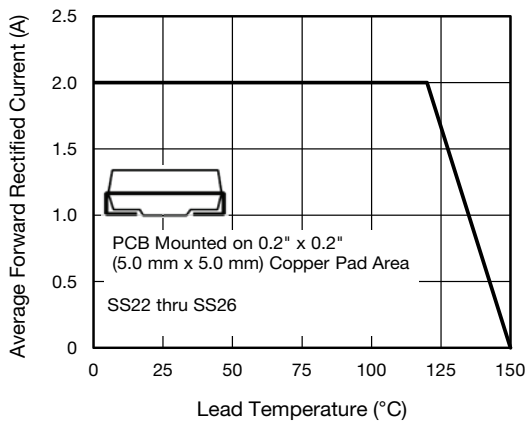


Fig. 1 - Forward Current Derating Curve

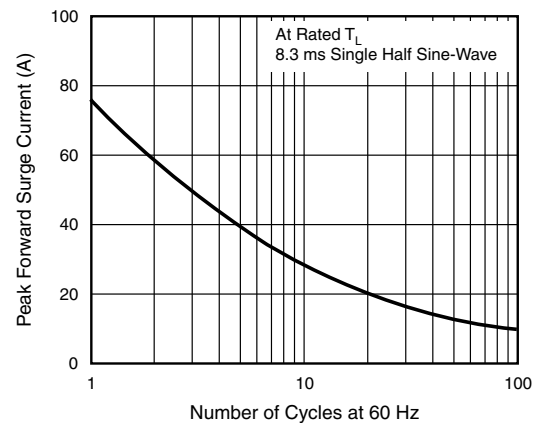


Fig. 2 - Maximum Non-Repetitive Surge Current

SS22, SS23, SS24, SS25, SS26

General Semiconductor

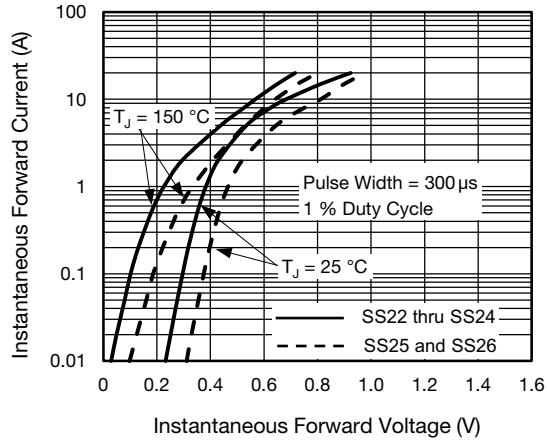


Fig. 3 - Typical Instantaneous Forward Characteristics

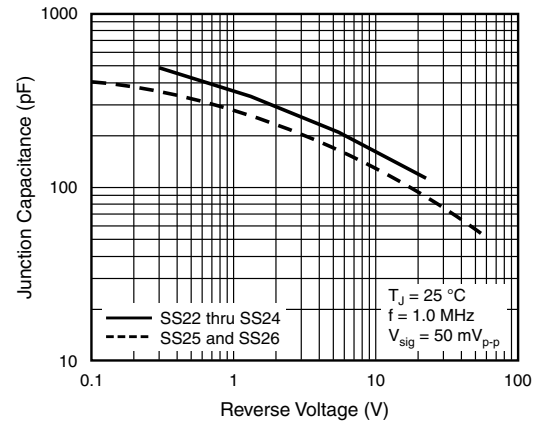


Fig. 5 - Typical Junction Capacitance

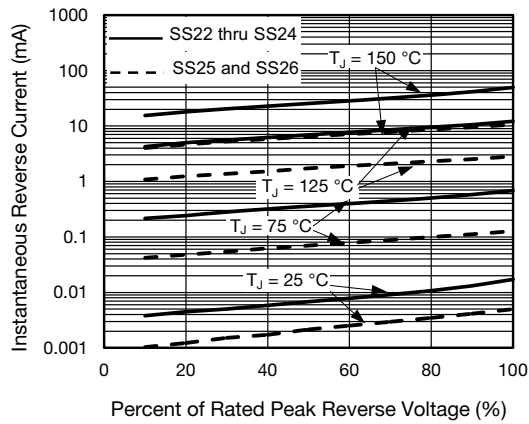


Fig. 4 - Typical Reverse Current Characteristics

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

